

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/611,602	06/30/2003	Mike Hermes	MI22-2341	6154
21567 75	590 03/16/2005		EXAMINER	
WELLS ST. JOHN P.S. 601 W. FIRST AVENUE, SUITE 1300			POMPEY, RON EVERETT	
SPOKANE, W	-		ART UNIT PAPER NUMBER	
			2812	
			DATE MAILED: 03/16/2005	5

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
Office Action Cummen.	10/611,602	HERMES, MIKE	<i>;</i>		
Office Action Summary	Examiner	Art Unit			
	Ron E. Pompey	2812	•		
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with	the correspondence addres	S		
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repl - If NO period for reply is specified above, the maximum statutory period of Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	I36(a). In no event, however, may a repl ly within the statutory minimum of thirty (3 will apply and will expire SIX (6) MONTH e, cause the application to become ABAN	y be timely filed 30) days will be considered timely. S from the mailing date of this commu	nication.		
Status					
1) Responsive to communication(s) filed on	•				
	action is non-final.				
3) Since this application is in condition for allowa	nce except for formal matter	s, prosecution as to the me	erits is		
closed in accordance with the practice under E					
Disposition of Claims	•				
4) Claim(s) 27-49 is/are pending in the applicatio	n.				
4a) Of the above claim(s) is/are withdra					
5) Claim(s) is/are allowed.	•				
6)⊠ Claim(s) <u>27-49</u> is/are rejected.					
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/o	or election requirement.				
Application Papers					
9)☐ The specification is objected to by the Examine	er.	•			
10)⊠ The drawing(s) filed on 30 June 2003 is/are: a)⊠ accepted or b)□ objecte	ed to by the Examiner.	•		
Applicant may not request that any objection to the	drawing(s) be held in abeyance	. See 37 CFR 1.85(a).			
Replacement drawing sheet(s) including the correct	tion is required if the drawing(s)	is objected to. See 37 CFR 1	.121(d).		
11)☐ The oath or declaration is objected to by the Ex	xaminer. Note the attached C	Office Action or form PTO-1	52.		
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreign	nriority under 35 U.S.C. & 1	19(a)-(d) or (f)	•		
a) ☐ All b) ☐ Some * c) ☐ None of:	i phonty under 55 0.0.0. g 1	19(a)-(d) 01 (l).			
	1. Certified copies of the priority documents have been received.				
2. Certified copies of the priority document		olication No.			
3. Copies of the certified copies of the prio	• •		ge		
application from the International Bureau					
* See the attached detailed Office action for a list	of the certified copies not re	ceived.			
· · · · · · · · · · · · · · · ·					
Attachment(s)					
1) Notice of References Cited (PTO-892)	4) Interview Sun	nmary (PTO-413)			
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/N	Mail Date			
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	5) Motice of Info	rmal Patent Application (PTO-152)		

Application/Control Number: 10/611,602

Art Unit: 2812

DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 27-49 rejected under 35 U.S.C. 103(a) as being unpatentable over Dennison (5,292,677) in further view of Arima (US 5,612,241).

Dennison discloses the steps of:

forming a plurality of conductive lines over a substrate having a memory array area and peripheral area outward of the memory array area;

removing insulative material, insulative cap (fig. 6B), over and exposing conductive material (26, fig.1) of conductive lines which are formed within a peripheral area outward of the memory array area, said exposing being a first-in-time exposure of conductive material of the conductive lines in the peripheral area after provision of said insulative material there over;

wherein the insulative material comprises a first insulative material, and further comprising prior to the removing of the first insulative material:

contemporaneously forming both capacitor container openings (41 fig. 2) within a second insulative material (32, fig. 2) over conductive lines within the memory array area, and contact openings (38, fig. 2) within the second insulative material over the conductive lines within the peripheral area;

Application/Control Number: 10/611,602

Art Unit: 2812

forming a pair of capacitor electrode layers, storage node (42, fig. 6A) and cell plate (52, fig. 6A), and an intervening dielectric (50, fig. 6A) region therebetween within the capacitor container openings and the contact openings (col.12, Ins. 11-52);

removing the capacitor electrode layer from within the contact openings and not from within the capacitor container openings (fig. 6B); and

wherein the removing: of the first insulative material comprises using an etch chemistry effective to remove both the first insulative material (fig. 6B) and selected portions of the capacitor electrode layer over the memory array (col. 10, In. 45 – col. 14, In. 31).

3. Dennison discloses all the limitations of claims except for:

forming conductive material over the substrate comprising:

conductive plugs received over substrate node locations over which storage capacitors are to be formed within a memory array area; and

conductive material received over portions of some of the conductive lines within the peripheral area.

However, Arima, discloses:

forming conductive material over the substrate comprising:

conductive plugs (15, fig. 3C) received over substrate node locations over which storage capacitors are to be formed within a memory array area; and

conductive material received over portions (16, fig. 3C) of some of the conductive lines within-the peripheral area (col. 6, lns. 52-61).

Art Unit: 2812

Therefore it would be obvious to do for one of ordinary skill in the art, to combine Arima with Dennison, because the conductive plug will provide for better electrical contact to the memory device and peripheral devices.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ron E. Pompey whose telephone number is (571) 272-1680. The examiner can normally be reached on compressed.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael S. Lebentritt can be reached on (571) 272-1873. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Ron Pompey AU:2812

March 5, 2005

MICHAEL LEBENTRITT
SUPERVISORY PATENT EXAMINER